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The Structural, morphological and optical properties of Ca doped TiO₂ thin films prepared by sol-gel method

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Abstract

The pure and Ca doped TiO_2 thin films with 1-10% mol of Ca concentrations were prepared by sol-gel method and deposited on glass substrates with dip-coating. All samples were annealed at 500 °C for 1 h and characterized by field emission scanning electron microscope (FESEM), UV-Vis spectrometer, and fluorescence spectrometer. From the experimental results, all thin film samples exhibited the anatase phase of crystalline structure. The surface morphology and crystal size were sensitive to Ca doping concentration. All of film samples displayed clearly higher 80% of transmission in the visible range. In additional, the fluorescence intensity of the thin films samples decreased with increasing the Ca doping concentrations.

Keywords: TiO2 thin films; Sol-gel; Dip-coating; Ca-doped

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1. Introduction

Titanium dioxide, TiO_2 is one of metal oxide as important materials due to their unique physical, optical and electrical properties e.g. high reflective index, transparency, wide band gap, stability at high electric filed, dielectric constant and nontoxic material [1-3]. The preparation and developed properties of TiO_2 material have widely studied. In general, there are many methods to fabricated thin films of TiO_2 such as sputtering [4], evaporation [5] and sol-gel method [6], etc. Among of these methods, Sol-gel is an interesting method to prepared TiO_2 thin film because it's simple technique, and easier to control compositions. Furthermore, the doping of TiO_2 with transition metal or non-metal ion has been extensively investigated for the purpose of improves its on physical electrical and optical properties [6-8]. The type and oxidation numbers of doping metals influenced to the oxygen distribution in the TiO_2 matrix and the dopant behavior to act as donors or acceptors. The efficiency of a dopant also depends on concentrations. The aim of this research work consists on the preparation of the pure and Ca doped TiO_2 thin films with sol-gel technique and deposited them on glass substrates with dip-coating method. The effects of doping Ca concentrations on structural, morphological and optical properties were investigated.

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2. Materials and methods

The Ca-doped TiO₂ thin films were fabricated by sol-gel and dip coating method. In a typical procedure, 100 mL of 0.20 M titanium tetra-isopropoxide were prepared in isopropanol under continuous stirring. Calcium nitrate tetrahydrate was added to the above solution by varying the concentration of Ca from 1 to 10 mol % and then small amounts of deionized water was dropped into the previous precursor solution. The solution was stirred for 10 min before being added nitric acid to adjust a pH of solution until the pH of the solution was equal to 2. Each precursor solution was further stirred at room temperature for 1 h until the homogeneous solution was obtained. The precursor solution was coated on glass substrate using the dip coating method. The as-prepared films were dried at 90 °C in air for 10 min to remove an organic solvent in the films. Finally, the dried films were annealed at 500 °C for 1 h.

The surface morphology of the thin films was characterized by FESEM (Hitachi, S-4700). The phase analysis was carried out by Raman spectroscopy (NT-MDTNTEGRA spectra). The optical properties in the range of 300 – 900 nm of thin films were carried out by a UV-vis spectrophotometer (Shimadzu 2600). The fluorescence behavior was investigated by fluorescence spectrophotometer (Cary Eclipse) with an excitation wavelength of 310 nm.

3. Results and Discussion

The Raman spectrometer was widely used for structural and phase identifications of TiO₂ thin films. X. Chen and S.S. Mao reported [9], the Raman peak of the TiO₂- anatase phase has six Raman-active modes at 144, 197, 399, 513 and 639 cm⁻¹. The TiO₂-rutile phase has four peak of vibrational modes around 145 cm⁻¹, 445 cm⁻¹, 610 cm⁻¹, and 240 cm⁻¹ (second order) [10]. Fig. 1(a) shows the Raman signal of pure and Ca-doped TiO₂ thin film samples. The Raman spectrum of pure TiO₂ thin film shows five peaks around 140 cm⁻¹, 193 cm⁻¹, 394 cm⁻¹, 515 cm⁻¹ and 631 cm⁻¹ which confirm the presence of anatase phase without the rutile and brookite phases.

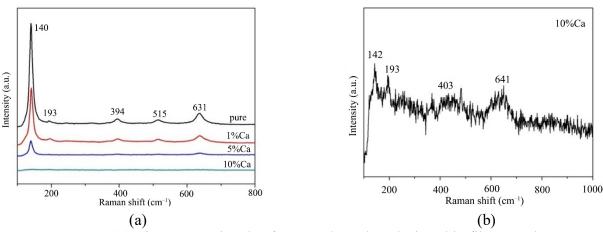


Fig. 1 (a) The Raman signals of pure and Ca-doped TiO₂ thin film samples. (b) The expanded Raman signals of 10% Ca doped TiO₂ film samples.

The Raman spectrum of 1% and 5% Ca-doped TiO₂ does not shift the peak position corresponding to anatase phase. However, the Ca concentrations affect the intensity and broadness of the Raman peaks. The Raman spectrum of the 10% Ca-doped TiO₂ thin film as shown in Fig. 1(b) displayed peak positions with appreciably estimated around 142 cm⁻¹, 193 cm⁻¹, 403 cm⁻¹, and 641 cm⁻¹. According to literature, the change in the width and shift of the Raman peaks is involved with the number of the impurity defects. The Ca doping in TiO₂ thin film less than 5% Ca does not affect the crystal size and

structure of the films. It was slight change in the symmetry of the crystals due to the distortions of lattice which produced from defect with Ca ions substitutes [11].

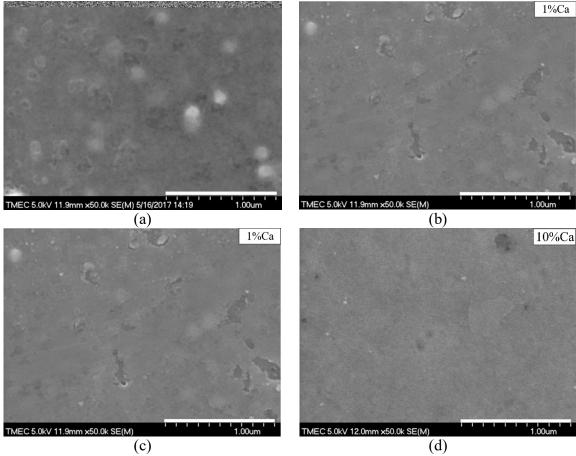


Fig. 2 FESEM images of the prepared thin film samples (a) pure and (b) - (d) 1%, 5% and 10% Ca doped, respectively.

Fig. 2 shows the FESEM image of pure, 1%, 5% and 10% Ca-doped of TiO₂ thin film samples. The surface morphology of pure TiO₂ thin film (see Fig. 2(a)) has spherical particles with approximate sizes less than 100 nm. From Fig. 2(b), it can be seen that the surface morphology of Ca-doped TiO₂ film samples were slightly changed at 1% Ca-doping concentration. The microstructure and surface morphology of 5% and 10% Ca-doped were become smooth without cracks and pores.

The optical transmittance spectra at room temperature of pure and Ca-doped TiO_2 thin film samples were shown in Fig. 3. It can be observed that, the transmittance was almost similar for the pure and other Ca-doping concentrations. The average optical transmission in visible range of all of samples, pure and Ca-doped TiO_2 films was about 85%. It was probably due to the surface morphology has smooth and low roughness, which could result in less light scattering. The cut-off wavelength of transmission spectra of all samples was slightly shifted to short wavelength when the Ca concentration increases. These shifts can be attributed to some size effect and the thin film morphology. The optical transmission in 350-550 nm ranges of film samples show a slight increase and decrease in 550-900 nm when the Ca concentration increases might be related to the scattering and/or absorption.

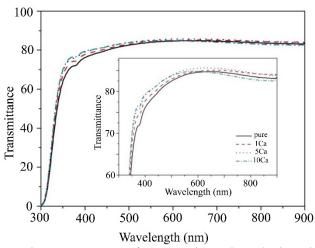


Fig. 3 Optical transmittance spectra of pure and Ca-doped TiO₂ thin film samples.

Fig. 4 shows the fluorescence spectra of pure and Ca doped TiO₂ thin film samples measured by an excitation wavelength of 310 nm at room temperature. It can be seen that the board emission peaks were observed at 366, 423, 488 and 495 nm. The emission peak at 363 nm was attributed to the direct transition from the conduction band to the valence band [12]. The slightly emission peak at 423 nm that can be observed from pure and 1% Ca doping might be attributed to the mediated transition by defect levels in the band gap [13]. While, the emission peaks were located about 488 and 495 nm arise from the charge transfer of an oxygen vacancy trapped electron [14, 15]. However, the intensity of fluorescence spectra decreased with increasing Ca concentration. This result might be attributed to the reduction of defects and variation of crystalline size of Ca doped TiO₂.

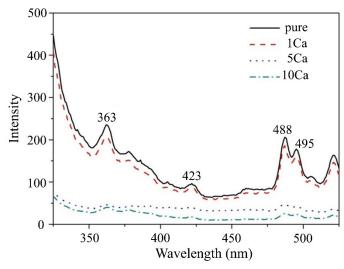


Fig. 4 Fluorescence spectra of pure and Ca doped TiO₂ thin film samples.

4. Conclusion

In this work, Ca doped TiO₂ thin film samples were prepared glass substrate by sol-gel dip coating method. The Raman results showed pure anatase structures for Ca doped TiO₂ thin films without any impurity phased. Optical transmittance spectra of the samples indicated that all thin films were similarly transparent approximate 85% in the visible range. The surface morphology of Ca-doped TiO₂ thin films were smooth and low roughness and tended to form denser when increasing Ca concentration. The fluorescence measurements showed the fluorescence peaks in the visible region

which can be ascribed to the presence of defect level and variation of the crystalline size when the Ca concentration increases.

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6. References

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